Mansoura university

Faculty of Engineering

Basic Electronics Exam. 21-1-2012 3 H.

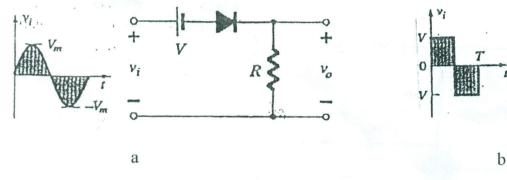
Computer Dept.

## Answer the following questions:

Q1)a-Draw and Explain briefly the structure and operation of P-N junction diode.

b-Is the depletion region width of P-N junction diode is larger or smaller in forward bias than in reverse bias ? Why?

- Q2) Determine the value of Vo for the circuits shown in Fig.1
- Q3) Determine IB and VcB for the circuit shown in Fig.2.
- Q4) Determine Rc , R<sub>E</sub> , and R<sub>B</sub> for the circuit shown in Fig.3 , if  $I_{Csat}$  =10 mA ,  $V_c$ = 20v ,  $I_c$ =4mA ,  $\beta$ =100.
- Q5)a-Draw and Explain the operation of P-channel JFET. b- Explain the CMOS as inverter.
- Q6) Determine  $I_{DQ}$ ,  $V_{GSQ}$ ,  $V_D$ ,  $V_S$ ,  $V_{DS}$ ,  $V_{DG}$ , for the circuit shown in Fig.4, if  $I_{DSS}$  =10 mA, and  $V_P$  =-8 v.



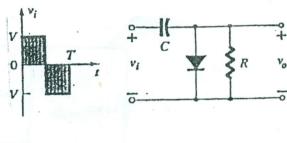


Fig.1

